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Charge-induced electromechanical actuation of Mo- and W-dichalcogenide monolayers

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Using first-principle density functional calculations, we investigate electromechanical properties of two-dimensional MX_2 ($M = \text{Mo}, \text{W}; X = \text{S}, \text{Se}, \text{Te}$) monolayers with the 1H and 1T structures as a function of charge doping for both electron and hole doping. We find that by increasing the atomic number, Z_X , of X atoms ($Z_S < Z_{\text{Se}} < Z_{\text{Te}}$), the work density per cycle of the MX_2 monolayers are increased and decreased for the 1H and 1T structures, respectively. On the other hand, the work density per cycle of the WX_2 monolayers are higher than that of the MoX_2 monolayers for both the 1H and 1T structures. Therefore, WTe_2 and WS_2 monolayers for the 1H and 1T structures, respectively, have the best electromechanical performances in the MX_2 compounds. In addition, the MX_2 monolayers show a reversible strain up to 3%, which is higher than that of graphene ($\sim 1\%$). Our results provide an important insight into the electromechanical properties of the MX_2 monolayers, which are useful for artificial muscles applications.

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1 Introduction

Artificial muscles or electromechanical actuation based on two-dimensional (2D) materials have become attractive recently because of its excellent properties such as larger surface doping, mechanical flexibility and thermal/chemical stability.^{1–5} For example, Xie *et al.*⁶ reported the superior strain response of a 2D graphene actuator, which has a strain approaching to 0.85%, exceeding that of the best-known CNT-based actuators. On the other hand, Ge *et al.*⁷ showed that an actuator based on the graphene oxide film is able to lift more than eight times its own weight. Very recently, Lu *et al.*⁸ reported a 2D graphdiyne-based electromechanical actuator with a high strain of up to 6.03%, and its energy density (11.5 kJ m^{-3}) is comparable to that of mammalian skeletal muscle ($\sim 8 \text{ kJ m}^{-3}$). However, the 2D artificial muscles based on graphene, graphene oxide, and graphdiyne have still been limited in the large-scale applications such as biomedicine and rehabilitation devices because these actuator materials are expensive and difficult to synthesize. Therefore, finding new 2D actuator materials with low manufacturing cost and large strain amplitude for the artificial muscles should be necessary.

Transition-metal dichalcogenides (TMDs) such as MX_2 ($M = \text{Mo}, \text{W}; X = \text{S}, \text{Se}, \text{Te}$) have similar layered structures as graphene.^{9,10} The chemically exfoliated MoS_2 nanosheets are synthesized by organo-lithium chemistry. By characteristics such as large-area two-dimensional flakes, thermodynamically stable and high quality, the 2D MoS_2 nanosheets have very attracted for artificial muscles on a large scale applications. Recently, Acerce *et al.*¹¹ showed a significant performance on the electromechanical actuation of the 2D MoS_2 nanosheets by using the intercalation reactions. They reported that the mechanical stress, strain, and work density of the MoS_2 nanosheets reach about 17 MPa, 0.8%, and 81 kJ m^{-3} , respectively. However, their study has limited to the MoS_2 nanosheets with only 1T structure. By using the density functional theory (DFT) calculations, Hung *et al.*¹² investigated the actuator performance of the MoS_2 monolayer with the 1H, 1T and 1T' structures. They pointed out that the actuator performance of the MoS_2 monolayers with the 1T and 1T' structures are better than that of the 1H structure. This because the interplay between the actuation strain and Young's modulus of the MoS_2 monolayer with difference structures. Both experiment and theory^{11,12} only focused of the MoS_2 monolayer actuator, while the actuator properties of other TMDs are not fully explored yet, except for some limited experiments.¹³ In this sense, a systematic theoretical design of many TMDs materials could be the first step to suggest possible structures suitable as highest electromechanical actuators. Moreover, TMDs have been demonstrated that the 1H structure is more dominant than the 1T and 1T' structure in many experiments^{14–16} due to their low energy formation. Therefore, it is an important to find which TMD among MX_2 compounds has a high actuator performance with the 1H structure.

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In this paper, we use the first-principles calculations within DFT to calculate the electromechanical properties of the MX_2 monolayers with a variety of M (M = Mo, W) and X (X = S, Se, Te) atoms as a function of charge doping for both electron and hole doping. As the main highlight of this paper, we summarize all the periodic trends strictly obeyed by our data including the Young's modulus, work density per cycle and actuator stress for both 1H and 1T structures of the MX_2 monolayers. Our results show that WTe_2 and WS_2 monolayers with the 1H and 1T structures, respectively, have the best electromechanical performances in the MX_2 compounds at heavy electron doping.

2 Methodology

The density-functional theory are performed to calculate the electromechanical actuator of the MX_2 monolayers using the Quantum ESPRESSO package.¹⁷ The pseudopotentials from the Standard Solid-State Pseudopotentials library are used.¹⁸ The exchange-correlation energy is evaluated by the general gradient approximation using the Perdew–Burke–Ernzerhof¹⁹ function. The cutoff energy of plane wave is set at 60 Ry, and $16 \times 16 \times 1$ k -point mesh of Monkhorst–Pack scheme is used for Brillouin zone integrations.²⁰

The atomic structures of the MX_2 monolayers with the 1H and 1T structures are shown in Fig. 1. The atomic positions and cell vectors of the MX_2 monolayers are fully relaxed to obtain optimized atomic configurations by using the Broyden–Fletcher–Goldfarb–Shanno minimization method^{21–24} until all the Hellmann Feynman forces and all components of the stress are less than 0.0005 Ry/a.u. and 0.05 GPa, respectively. The periodic boundary condition is applied in all models, a vacuum space of 30 Å in the direction perpendicular to the monolayer (z direction) is used in order to avoid virtual interactions between layers.

The geometry optimization is then performed for each charge doping from -0.1 to $+0.1$ electron per atom (e/atom) to consider the electromechanical actuation of the MX_2 monolayers. The electron (hole) doping is simulated by adding (removing) electrons to the unit cell with a uniform charge

background.^{25,26} The elastic constants C_{ij} of MX_2 monolayers are estimated by using the Themo-pw code.²⁷ Since the values of C_{ij} are related to the equivalent volume of the unit cell, the calculated C_{ij} must be rescaled by h/d_0 , where h is the length of the cell along z axis and d_0 is the effective layer thickness of the MX_2 monolayers ($d_0 = 6.145$ Å).¹² The Young's modulus, Y , and the Poisson's ratio, ν , of the MX_2 monolayers can be obtained from the following equation as¹²

$$Y = \frac{C_{11}^2 - C_{12}^2}{C_{11}}; \nu = \frac{C_{12}}{C_{11}} \quad (1)$$

The power of electromechanical actuators is characterized by the stress generated, $\sigma = Y\varepsilon$ where actuator strain ε is defined as $\Delta a/a_0$, where a_0 is the lattice constant at geometry optimization for neutral case, and Δa is increment (or decrement) of a_0 after the charge doping has been applied. The performance of electromechanical actuators is characterized by the work density per cycle, which is often expressed in terms of stored energy density W_s .¹² The formula for the work density per cycle is given by

$$W_s = \frac{1}{2} Y \varepsilon^2. \quad (2)$$

3 Results and discussion

In Table 1, we show the optimized lattice parameters of the MX_2 monolayers, in which the lattice parameters of the MoX_2 and WX_2 monolayers have quite similar values. The lattice constants of the MX_2 monolayers increase with increasing of atomic number of M, Z_M ($Z_{\text{Mo}} < Z_{\text{W}}$), and X, Z_X ($Z_{\text{S}} < Z_{\text{Se}} < Z_{\text{Te}}$), atoms. Our calculated results are in good agreement with previous theoretical results,^{9,28} indicating that the present calculations are reasonable and reliable. In addition the total energy of the MX_2 monolayers with the 1H structure (1H- MX_2) are smaller than that of the 1T structure (1T- MX_2). Therefore, the MX_2 monolayers with 1H structure are more stable than 1T structure. In many experiments, the 1H structure also was found to be

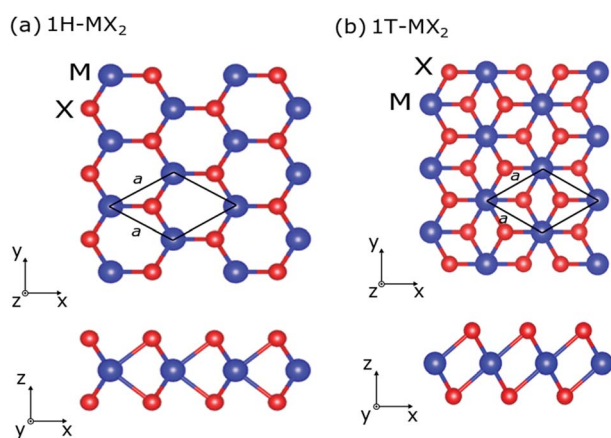


Fig. 1 Top and side view of the MX_2 monolayers with the 1H (a) and 1T structures (b), respectively.

Table 1 Lattice constant a_0 (Å), total energy E_{tot} (Ry), elastic constants C_{ij} (GPa), Young's modulus Y (GPa) and Poisson's ratio ν of the 1H- and 1T- MX_2 monolayers

MX_2	a_0	E_{tot}	C_{11}	C_{22}	C_{12}	C_{66}	Y	ν
1H-MoS ₂	3.19	-190.798	207	207	42	83	197	0.200
1H-MoSe ₂	3.31	-224.510	173	173	32	71	167	0.180
1H-MoTe ₂	3.55	-190.204	129	129	41	44	116	0.320
1T-MoS ₂	3.18	-190.739	169	169	-4.0	86	167	-0.020
1T-MoSe ₂	3.28	-224.462	166	166	-3.2	85	166	-0.019
1T-MoTe ₂	3.53	-190.169	140	140	-0.39	70	140	-0.003
1H-WS ₂	3.19	-597.594	230	230	43	94	222	0.185
1H-WSe ₂	3.32	-631.292	193	193	31	81	188	0.160
1H-WTe ₂	3.56	-596.969	140	140	27	57	135	0.190
1T-WS ₂	3.20	-597.530	171	171	-2.2	87	171	-0.013
1T-WSe ₂	3.29	-631.238	159	159	-9.3	84	159	-0.060
1T-WTe ₂	3.54	-596.931	136	136	-12	73	135	-0.086



abundantly in sample.^{29,30} We also note that MoTe₂ and WTe₂ monolayers might not have ideal 1T phase. They form the distorted 1T structure, namely 1T' structure.³¹ Since the MX₂ monolayers with 1T' structure exhibit an anisotropic behavior,^{12,31} in present study, we only focus on the isotropic 1H- and 1T-MX₂ monolayers.

To calculate the actuator response of the MX₂ monolayers, we firstly check the mechanical moduli at the neutral condition case ($q = 0$). The values of the elastic constants C_{ij} , Young's modulus Y and Poisson's ratio ν of the MX₂ monolayers are listed in Table 1. Y of the MX₂ monolayers decreases with increasing Z_X . On the other hand, by increasing Z_M , Y is increased and decreased for the 1H and 1T structures, respectively, expect that Y of the 1T-MoS₂ monolayer is smaller than that of the 1T-WS₂ monolayer. Therefore, the WS₂ monolayer shows the stiffest materials in the MX₂ compounds with $Y = 222$ GPa and $Y = 171$ GPa for the 1H and 1T structures, respectively. In addition, the Poisson's ratio is also an important mechanical properties. Our results show that ν of the 1H structures is positive, while ν of the 1T structures is negative. It is known that the negative Poisson's ratio are also found in other 2D materials such as in black phosphorus ($\nu = -0.5$),³² single-layer graphene ribbons ($\nu = -1.51$),³³ and δ -phosphorene ($\nu = -0.267$).³⁴ The 2D materials with native Poisson's ratio could have useful applications, for example, as vanes for aircraft gas turbine engines, sponges, and fasteners.³⁵

Although the atomic structures of the MX₂ monolayers has been optimized, they do not guarantee a dynamical stability under

the charge doping. Therefore, we analyze the generic elastic stability conditions for the MX₂ structures at each charge doping level. In particular, in the 2D hexagonal structure, the necessary and sufficient conditions of stability are $C_{11} > |C_{12}| > 0$ and $C_{66} > 0$.³⁶ In Fig. 2(a) and (b), we show the elastic constants (C_{11} , C_{12} and C_{66}) of the MX₂ monolayers as a function of charge doping q ranging from -0.1 to 0.1 e/atom for the 1H and 1T structures, respectively. Our results reveal that $C_{11} > |C_{12}| > 0$ and $C_{66} > 0$ for both all the 1H and 1T structures. Therefore, the MX₂ monolayers show a stable structure under both electron and hole doping cases. After revealing the stable configurations, the electromechanical properties of the MX₂ monolayers are investigated.

In Fig. 3(a) and (b), we show the Young's modulus Y of the 1H- and 1T-MX₂ monolayers, respectively, as a function of the charge doping ($q \neq 0$). For the 1H-MX₂ monolayers, Y decreases for both the electron ($q < 0$) and hole ($q > 0$) dopings, except that Y of the WS₂ monolayer is approximately constant for the hole doping case, as shown in Fig. 3(a). For the 1T-MX₂ monolayers, Y decreases and increases for the electron and hole dopings, respectively, except that Y of the MoTe₂ decreases for both electron and hole dopings, as shown in Fig. 3(b). We note that since $C_{12} \ll C_{11}$ (see Fig. 2), the Young's modulus in eqn (1) can be rewritten as $Y \sim C_{11}$ for both 1H- and 1T-MX₂ monolayers. Therefore, the behaviours of Y are similar to C_{11} under the electron and hole doping cases. The results obtained show that the maximum Y of the MX₂ monolayers are 222 GPa and 197 GPa for the 1H-WS₂ and 1T-MoS₂ monolayers, respectively, at $q = 0.1$ e/atom. Y of the MX₂ monolayers is thus comparable to that of

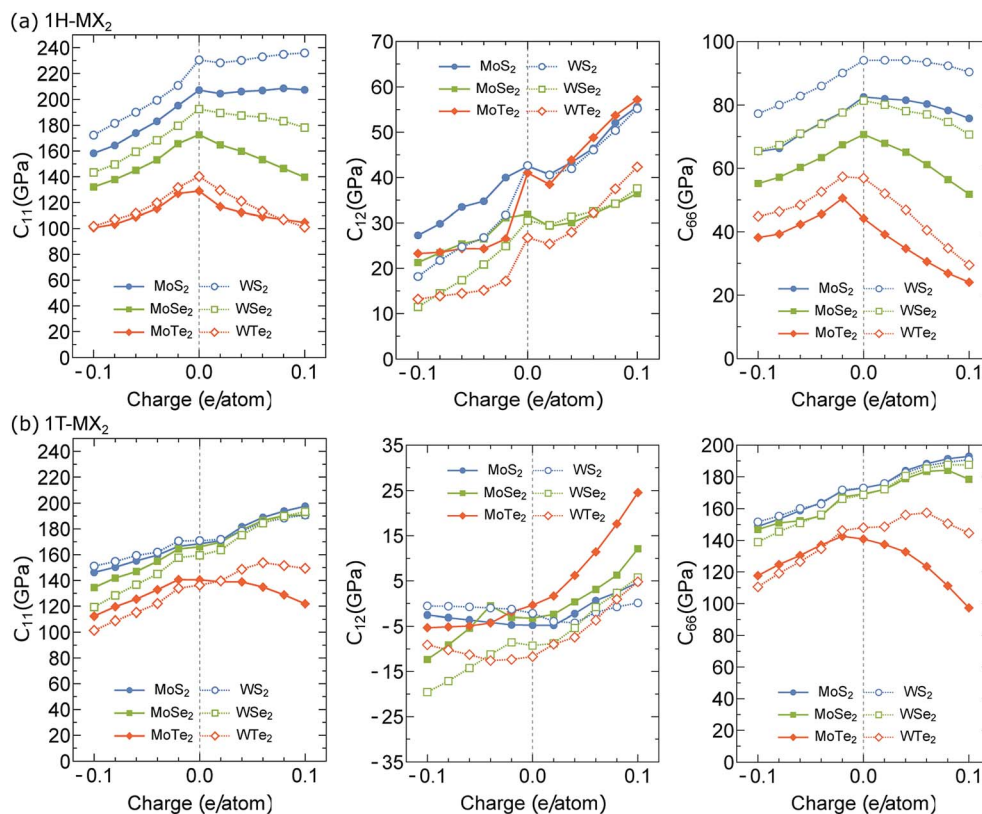


Fig. 2 Elastic constants C_{11} , C_{12} and C_{66} of the (a) 1H-MX₂ and (b) 1T-MX₂ monolayers plotted as function of charge (electron and hole) doping per atom.



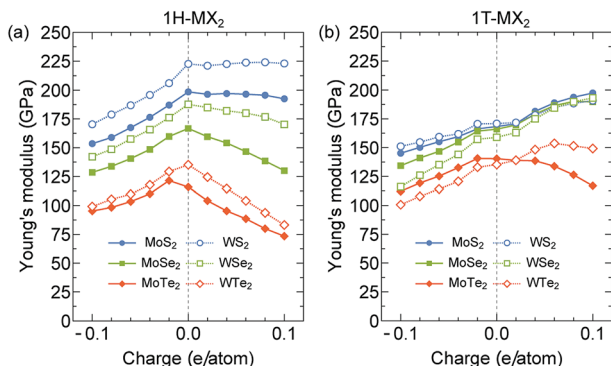


Fig. 3 Young's modulus of the (a) 1H-MX₂ and (b) 1T-MX₂ monolayers plotted as a function of charge doping per atom.

the stainless steel (192 GPa).³⁷ It notes that the materials with high Y value can generate large force per unit area.

In Fig. 4(a) and (b), we show the actuator strain ε of the 1H- and 1T-MX₂ monolayers as a function of charge doping q ranging from -0.1 to 0.1 e/atom. In the neutral case ($q = 0$), we obtain $\varepsilon = 0$. For the charge doping case, ε is approximately a linear function of q for electron doping ($q < 0$), while it is non-linear function of q for hole doping ($q > 0$). As shown in Fig. 4(a), the absolute values of ε of the 1H-MX₂ monolayers mainly depend on X atoms, in which $MTe_2 > MSe_2 > MS_2$ for both electron and hole doping cases. In contrast, the absolute values

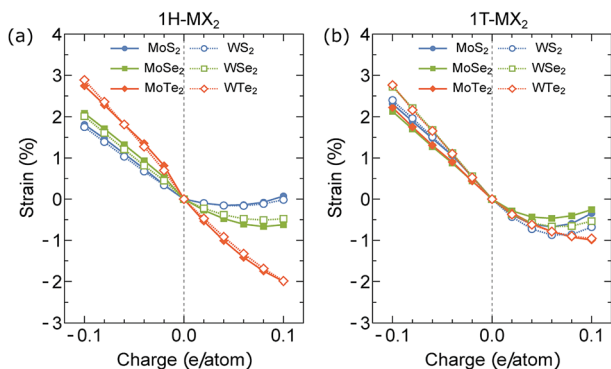


Fig. 4 Strain as function of charge doping per atom of monolayer (a) 1H-MX₂, (b) 1T-MX₂.

of ε of the 1T-MX₂ monolayers mainly depend on M atoms ($WX_2 > MoX_2$), as shown in Fig. 4(b). For the MoS₂ monolayer, the strain of the 1T structure (2.25%) is higher than that of the 1H structure (1.78%) at $q = -0.1$ e/atom. The MoS₂ monolayer with the 1T structure is thus predicted high actuation performance, which is consistent with previous results.¹² As shown in Fig. 4(a) and (b), unlike the MS₂ and MSe₂ monolayers, the strain of the MTe₂ monolayers (MoTe₂ and WTe₂) with the 1H structure are higher than that with the 1T structures. The highest ε is found in the MoTe₂ (2.74%) and WTe₂ (2.9%) monolayers with the 1H structure at $q = -0.1$ e/atom, respectively, which is higher than that of carbon nanotubes and graphene ($\sim 1\%$).^{6,25,38} Since the 1H structure is dominates in the TMDs structures, the MoTe₂ and WTe₂ monolayers may be the ideal choice for the artificial muscles. In order to understand these behaviors of the actuator strain, the bond lengths between M and X atoms are investigated at different charge doping level, as shown in Fig. 5. In the neutral case ($q = 0$), the M (Mo, W)-Te bond lengths of 1H- and 1T-MX₂ are higher than the M-Se and M-S bond lengths, respectively. For the electron doping, the M-X bond lengths increase linearly by increasing q ($q < 0$), while they increase non-linearly for the hole doping ($q > 0$). As shown in Fig. 5(a)-(c), the electron doping largely change the M-X bond lengths compared with the hole doping. We note that the electron doping will “pull down” many interlayer bands in the TMDs band structure, while hole doping do not.¹² Such a phenomenon might contribute to the higher strain actuators by the electron doping rather than the hole doping.

In Fig. 6(a) and (b), we show the actuator stress of the MX₂ monolayers as a function of charge doping for the 1H and 1T structures, respectively. In the neutral case ($q = 0$), we obtain $\sigma = 0$ because $\varepsilon = 0$. For the electron doping ($q < 0$), the stress of the MX₂ monolayers with both the 1H and 1T structures increases with increasing $|q|$. The highest stresses are found in the WS₂ monolayers for both the 1H ($\sigma = 3$ GPa) and 1T structures ($\sigma = 3.6$ GPa) due to their highest Young's modulus as shown in Fig. 3. For the hole doping ($q > 0$), the highest stress of the MX₂ monolayers with the 1H structure is found in the WTe₂ monolayers with $\sigma = -1.65$ GPa at $q = 0.1$ e/atom, while it is found in WS₂ monolayers with 1T structures ($\sigma = -1.62$ GPa at $q = 0.1$ e/atom).

Finally, we investigate the performance of the electromechanical actuators of the MX₂ monolayers. In Fig. 7(a) and (b),

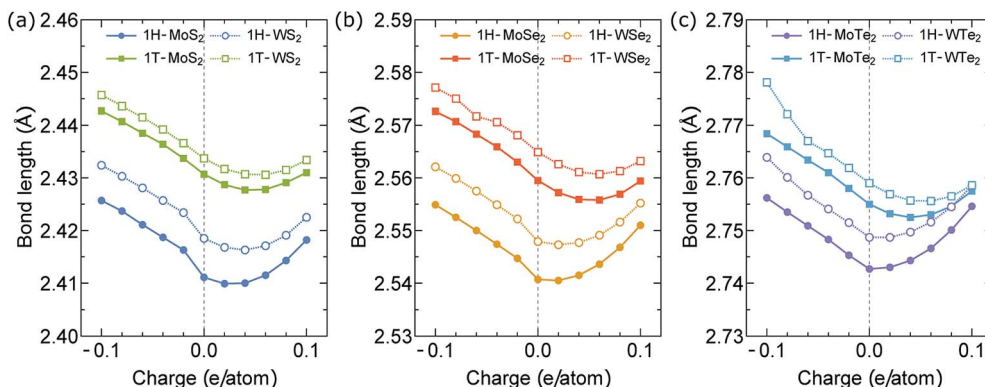


Fig. 5 M-X bond lengths as a function of the charge doping per atom (a) MS₂, (b) MSe₂ and (c) MTe₂.



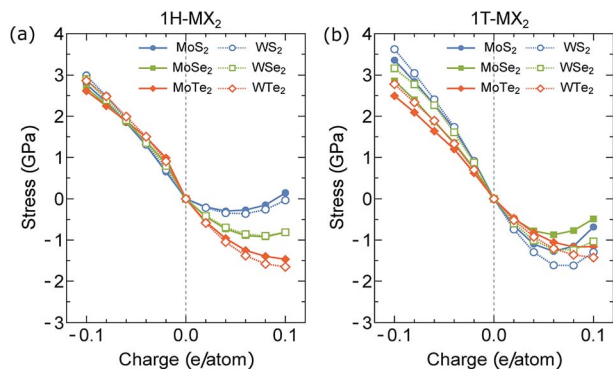


Fig. 6 Stress generated by (a) 1H-MX₂ and (b) 1T-MX₂ monolayers plotted as function of charge doping per atom.

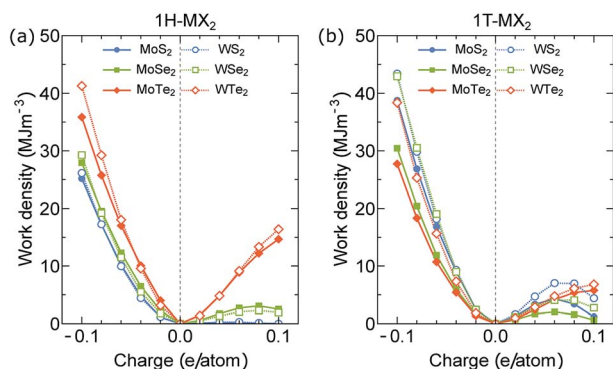


Fig. 7 Work density per cycle of the (a) 1H-MX₂ and (b) 1T-MX₂ monolayers plotted as function of charge (electron and hole) doping per atom.

we show the work density per cycle W_s of the 1H- and 1T-MX₂ monolayers as a function of charge doping, respectively, in which the W_s is determined by eqn (2). For the electron doping ($q < 0$), W_s of the MX₂ monolayer with both 1H and 1T structures increases with increasing $|q|$. In the meantime, W_s is increased and decreased with increasing Z_X ($Z_S < Z_{Se} < Z_{Te}$) for the 1H and 1T structures, respectively. On the other hand, W_s of the MoX₂

monolayers is smaller than that of the WX₂ monolayers for both 1H and 1T structures. Therefore, the highest W_s is found in the WTe₂ (41.66 MJ m⁻³) and WS₂ (43.30 MJ m⁻³) monolayers with the 1H and 1T structures at $q = -0.1$ e/atom, respectively. These work density per cycle are more than 1000 times that of skeleton muscle (~ 0.04 MJ m⁻³)³⁹ and 7 times that of Au-Pt alloys (~ 6 MJ m⁻³)^{40,41} due to their high Young's modulus and high actuator strain. For the hole doping ($q > 0$), the maximum W_s is found in the WTe₂ (16.4 MJ m⁻³ at 0.1 e/atom) and WS₂ monolayers (7.03 MJ m⁻³ at 0.06 e/atom) for the 1H and 1T structures, respectively. W_s at the electron doping case is thus higher than that of the hole doping case, which suggests that the electron doping should be good to achieve high-performance actuator in the artificial muscle application. All the periodic trends strictly obeyed by our data are summarized for the electron doping at $q = -0.1$ e/atom are shown in Fig. 8.

4 Conclusion

In summary, we have investigated the actuator performance of the two-dimensional MX₂ monolayers with the 1H and 1T structures by first principles calculations. We find that the actuator performance of the MX₂ monolayers not only depend on the charge doping level but also the atomic numbers Z_M and Z_X of M and X atoms, respectively. The 1H-WTe₂ and 1T-WS₂ monolayers have the best electromechanical performances in the MX₂ compounds with the work density per cycle can be achieved up to 41.66 MJ m⁻³ and 43.30 MJ m⁻³ under charge doping, respectively. Moreover, the MX₂ monolayers show the reversible strain up to 3%. The results of this study are useful for the design and fabricating of artificial muscles with the MX₂ compounds.

Conflicts of interest

There are no conflicts to declare.

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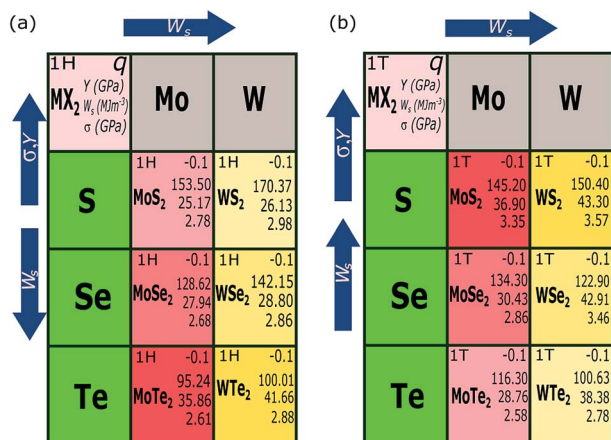


Fig. 8 Trends in work density per cycle, stress and Young's modulus of (a) the 1H-MX₂ and (b) 1T-MX₂ monolayers for the electron doping at $q = -0.1$ e/atom.



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